

# RJH60F7DPQ-A0

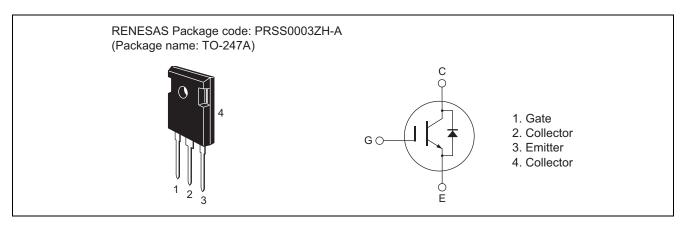
## Silicon N Channel IGBT High Speed Power Switching

R07DS0328EJ0100 Rev.1.00 Apr 06, 2011

#### **Features**

- Low collector to emitter saturation voltage  $V_{CE(sat)}=1.35$  V typ. (at  $I_C=50$  A,  $V_{GE}=15$  V, Ta=25°C)
- Built in fast recovery diode in one package
- Trench gate and thin wafer technology
- High speed switching  $t_f = 74 \text{ ns typ. (at } I_C = 30 \text{ A}, \ V_{CE} = 400 \text{ V}, \ V_{GE} = 15 \text{ V}, \ Rg = 5 \ \Omega, \ Ta = 25 ^{\circ}C, \ inductive \ load)$

#### **Outline**



### **Absolute Maximum Ratings**

 $(Tc = 25^{\circ}C)$ 

Item		Symbol	Ratings	Unit
Collector to emitter voltage		V <sub>CES</sub>	600	V
Gate to emitter voltage		$V_{GES}$	±30	V
Collector current	Tc = 25°C	Ic	90	А
	Tc = 100°C	Ic	50	А
Collector peak current		ic(peak) Note1	180	А
Collector to emitter diode forward peak current		i <sub>DF</sub> (peak) Note2	100	А
Collector dissipation		Pc	328.9	W
Junction to case thermal impedance (IGBT)		θј-с	0.38	°C/W
Junction to case thermal impedance (Diode)		θj-cd	2.0	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. Pulse width limited by safe operating area.

2. PW  $\leq$  5  $\mu$ s, duty cycle  $\leq$  1%

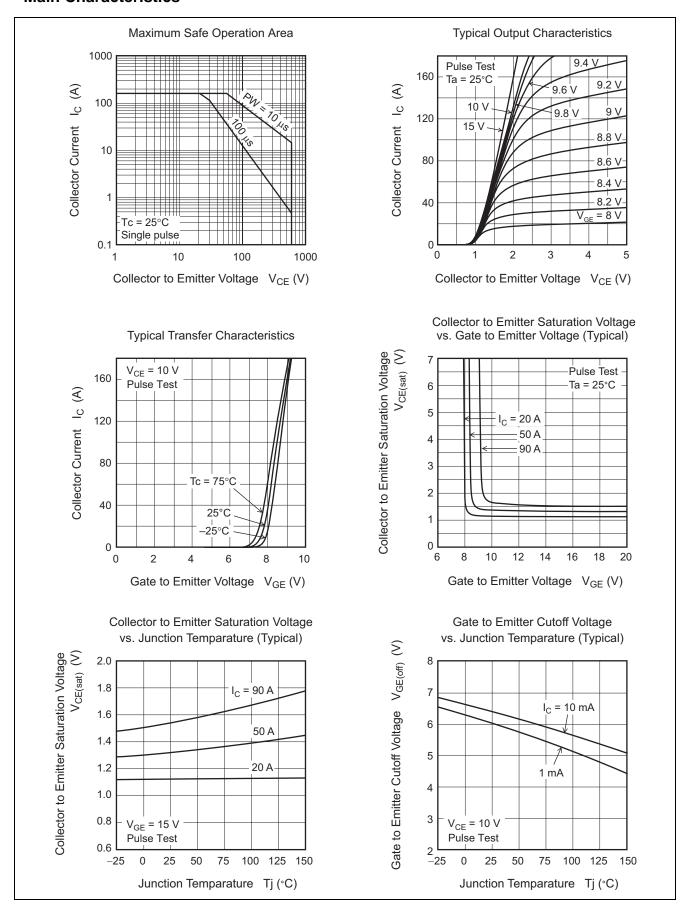
## **Electrical Characteristics**

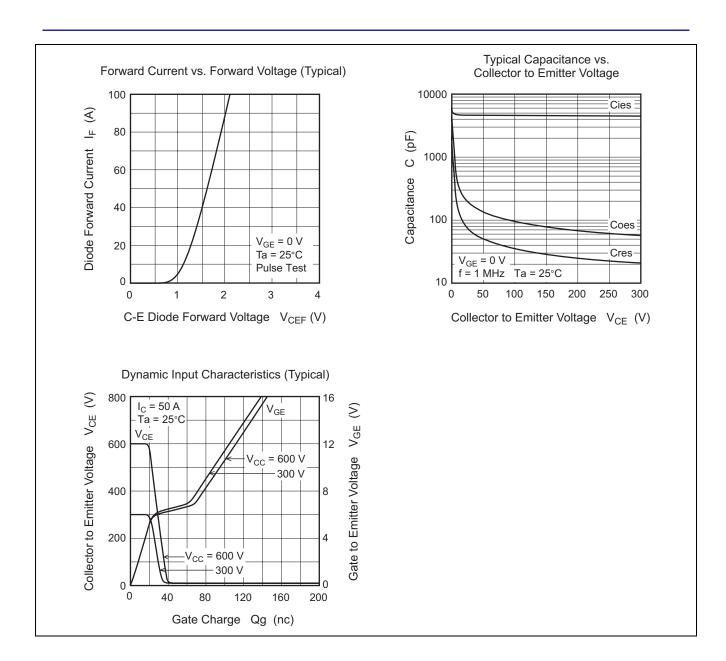
 $(Tj = 25^{\circ}C)$ 

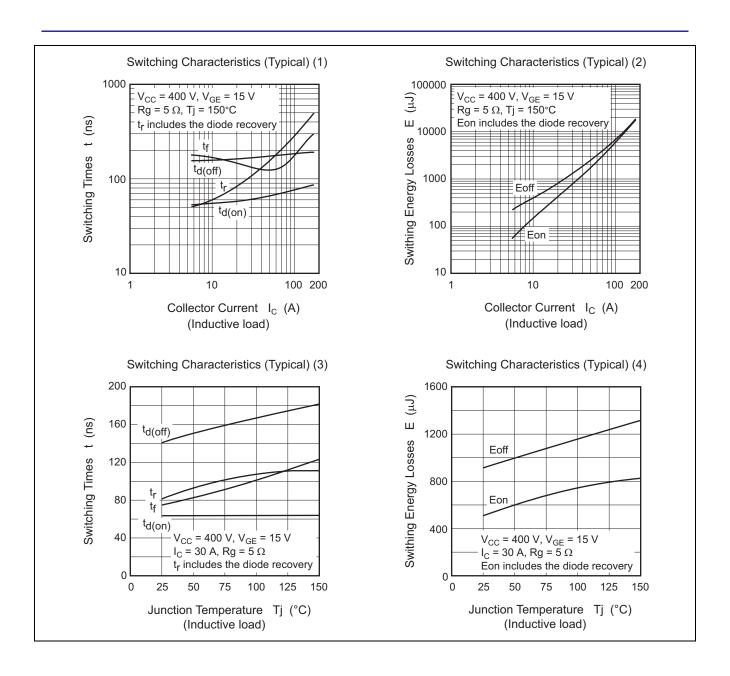
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Zero gate voltage collector current	I <sub>CES</sub>	_	_	100	μΑ	$V_{CE} = 600V, V_{GE} = 0$	
Gate to emitter leak current	I <sub>GES</sub>	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	$V_{GE(off)}$	4	_	8	V	$V_{CE} = 10V, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	1.35	1.75	V	$I_C = 50 \text{ A}, V_{GE} = 15 \text{V}^{\text{Note3}}$	
	V <sub>CE(sat)</sub>	_	1.6	_	V	$I_C = 90 \text{ A}, V_{GE} = 15V^{\text{Note3}}$	
Input capacitance	Cies	_	4700	_	pF	V <sub>CE</sub> = 25 V V <sub>GE</sub> = 0 V	
Output capacitance	Coes	_	198	_	pF		
Reverse transfer capacitance	Cres	_	83	_	pF	f = 1 MHz	
Switching time	t <sub>d(on)</sub>	_	63	_	ns	$I_C = 30 \text{ A},$ $V_{CE} = 400 \text{ V}, V_{GE} = 15 \text{ V}$ $Rg = 5 \Omega^{\text{Note3}}$ Inductive load	
	t <sub>r</sub>	_	81	_	ns		
	t <sub>d(off)</sub>	_	142	_	ns		
	t <sub>f</sub>	_	74	_	ns		
C-E diode forward voltage	V <sub>ECF1</sub>	_	1.2	2.1	V	I <sub>F</sub> = 20 A <sup>Note3</sup>	
	V <sub>ECF2</sub>	_	1.5	_	V	I <sub>F</sub> = 40 A Note3	
C-E diode reverse recovery time	t <sub>rr</sub>	_	90	_	ns	I <sub>F</sub> = 20 A	
						$di_F/dt = 100 A/\mu s$	

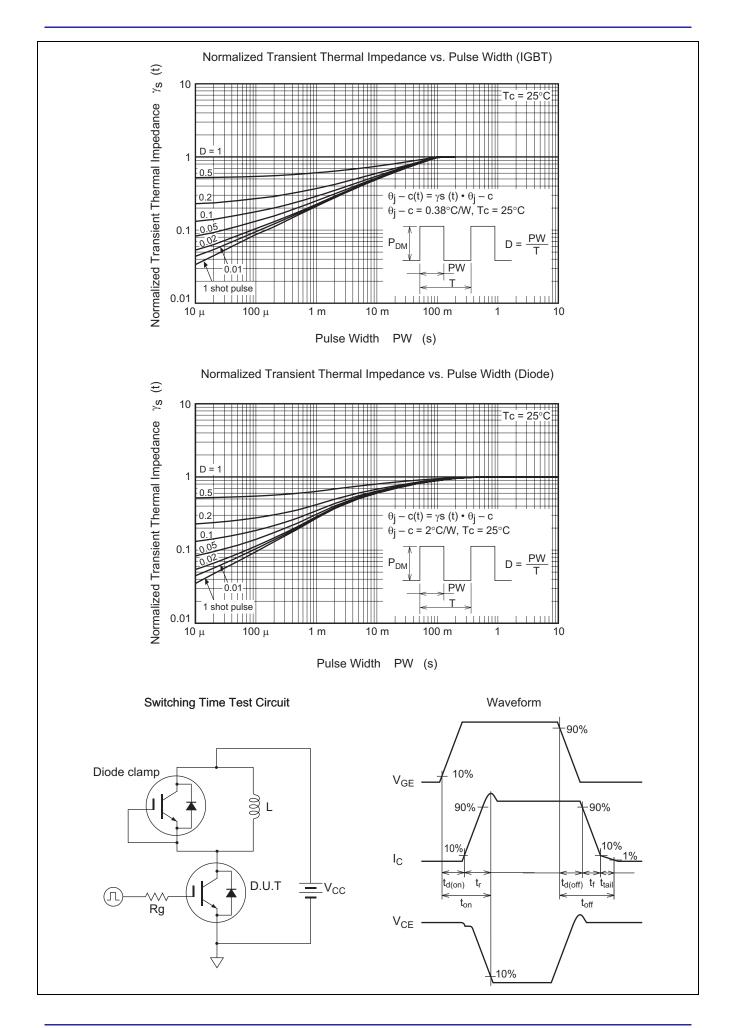
Notes: 3. Pulse test

#### **Main Characteristics**

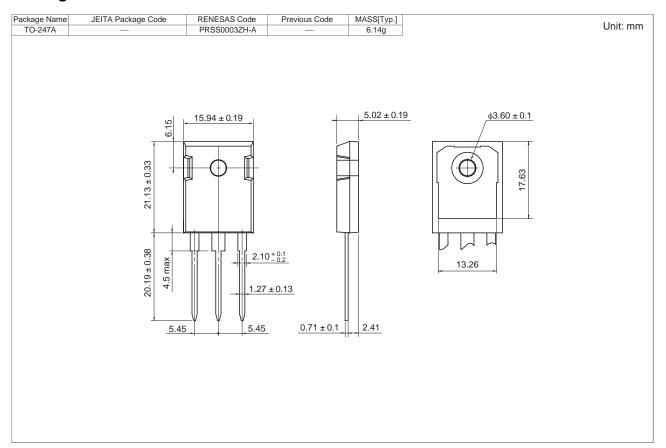








## **Package Dimensions**



## **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
RJH60F7DPQ-A0-T0	240 pcs	Box (Tube)

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